2:1 Mux/Demux Analog Switches

The NLAS1053 is an advanced CMOS analog switch fabricated with silicon gate CMOS technology. It achieves very high speed propagation delays and low ON resistances while maintaining CMOS low power dissipation. The device consists of a single 2:1 Mux/Demux (SPDT), similar to ON Semiconductor's NLAS4053 analog and digital voltages that may vary across the full power supply range (from VCC to GND).

The inhibit and select input pins have over voltage protection that allows voltages above V_{CC} up to 7.0 V to be present without damage or disruption of operation of the part, regardless of the operating voltage.

- High Speed: tpD = 1 ns (Typ) at VCC = 5.0 V
- Low Power Dissipation: $I_{CC} = 2 \mu A$ (Max) at $T_A = 25^{\circ}C$
- High Bandwidth, Improved Linearity, and Low RDSON
- INH Pin Allows a Both Channels 'OFF' Condition (With a High)
- RDSON \cong 25 Ω , Performance Very Similar to the NLAS4053
- Break Before Make Circuitry, Prevents Inadvertent Shorts
- Useful For Switching Video Frequencies Beyond 50 MHz
- Latch-Up Performance Exceeds 300 mA
- ESD Performance: HBM > 2000 V; MM > 200 V, CDM > 1500 V
- Tiny US8 Package, Only 2.1 X 3.0 mm

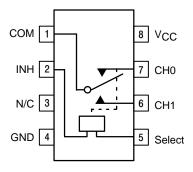


Figure 1. Pin Assignment



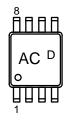
ON Semiconductor™

http://onsemi.com

MARKING DIAGRAMS



US8 US SUFFIX CASE 493-01



AC = Device Code D = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

FUNCTION TABLE

INH	Select	Ch 0	Ch 1
Н	Х	OFF	OFF
L	L	ON	OFF
L	Н	OFF	ON

NI AS1053

MAXIMUM RATINGS

Symbol	Pa	rameter	Value	Unit
VCC	Positive DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	Digital Input Voltage (Select and Inhibit)	-0.5 ≤ V is ≤ +7.0	V
V _{IS}	Analog Output Voltage (V _{CH} or V _{COM})	$-0.5 \le V \text{ is } \le V_{CC} +0.5$	V
liK	DC Current, Into or Out of Any Pin		50	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case fo	r 10 Seconds	260	°C
TJ	Junction Temperature under Bias		+150	°C
θ JA	Thermal Resistance		250	°C/W
PD	Power Dissipation in Still Air at 85°C		250	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 30% – 35%	UL-94-VO (0.125 in)	
VESD	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 200 N/A	V
ILatch-Up	Latch-Up Performance	Above V _{CC} and Below GND at 85°C (Note 5)	±300	mA

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
- 2. Tested to EIA/JESD22-A114-A.
- 3. Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit	
VCC	Positive DC Supply Voltage		2.0	5.5	V
VIN	Digital Input Voltage (Select and Inhibit)		GND	5.5	V
V _{IO}	Static or Dynamic Voltage Across an Off Switch		GND	VCC	V
VIS	Analog Input Voltage (CH, COM)		GND	VCC	V
T _A	Operating Temperature Range, All Package Types		-55	+125	°C
t _r , t _f	Input Rise or Fall Time, (Enable Input)	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0	100 20	ns/V

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

10 011/0 20112 1711201120							
Junction Temperature °C	Time, Hours	Time, Years					
80	1,032,200	117.8					
90	419,300	47.9					
100	178,700	20.4					
110	79,600	9.4					
120	37,000	4.2					
130	17,800	2.0					
140	8,900	1.0					

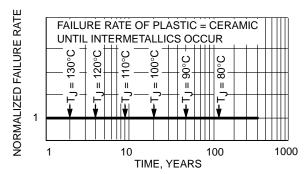


Figure 2. Failure Rate versus Time Junction Temperature

DC CHARACTERISTICS – Digital Section (Voltages Referenced to GND)

				Gua	ranteed Lim	nit	
Symbol	Parameter	Condition	Vcc	−55°C to 25°C	<85°C	<125°C	Unit
VIH	Minimum High-Level Input		2.0	1.5	1.5	1.5	V
	Voltage, Select and Inhibit Inputs		2.5	1.9	1.9	1.9	
	Inputs		3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			5.5	3.85	3.85	3.85	
V _{IL}	Maximum Low-Level Input		2.0	0.5	0.5	0.5	V
	Voltage, Select and Inhibit		2.5	0.6	0.6	0.6	
	Inputs		3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			5.5	1.65	1.65	1.65	
I _{IN}	Maximum Input Leakage Current, Select and Inhibit Inputs	V _{IN} = 5.5 V or GND	0 V to 5.5 V	± 0.1	±1.0	±1.0	μΑ
ICC	Maximum Quiescent Supply Current	Select and Inhibit = V _{CC} or GND	5.5	1.0	1.0	2.0	μΑ

DC ELECTRICAL CHARACTERISTICS - Analog Section

				Guaranteed Limit			
Symbol	Parameter	Condition	VCC	−55 to 25°C	< 85°C	< 125°C	Unit
RON	Maximum "ON" Resistance (Figures 17 – 23)	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $V_{IS} = GND \text{ to } V_{CC}$ $I_{IN}I \le 10.0 \text{ mA}$	2.5 3.0 4.5 5.5	70 40 20 16	85 46 28 22	105 52 34 28	Ω
R _{FLAT} (ON)	ON Resistance Flatness (Figures 17 – 23)	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{IN}I \le 10.0 \text{ mA}$ $V_{IS} = 1V, 2V, 3.5V$	4.5	4	4	5	Ω
ΔR _{ON} (ON)	ON Resistance Match Between Channels	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{INI} \le 10.0 \text{ mA}$ $V_{CH1} \text{ or } V_{CH0} = 3.5 \text{ V}$	4.5	2	2	3	Ω
I _{CH0} I _{CH1}	CH1 or CH0 Off Leakage Current (Figure 9)	V _{IN} = V _{IL} or V _{IH} V _{CH1} or V _{CH0} = 1.0 V _{COM} 4.5 V	5.5	1	10	100	nA
ICOM(ON)	COM ON Leakage Current (Figure 9)	VIN = VIL or VIH VCH1 1.0 V or 4.5 V with VCH0 floating or VCH1 1.0 V or 4.5 V with VCH1 floating VCOM = 1.0 V or 4.5 V	5.5	1	10	100	nA

AC ELECTRICAL CHARACTERISTICS (Input $t_f = t_f = 3.0 \text{ ns}$)

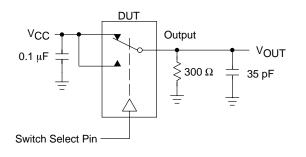
				(Guaranteed Max Limit						
			VCC	-5	5 to 25	°C	< 8	5°C	< 12	25°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур*	Max	Min	Max	Min	Max	Unit
tON	Turn–On Time (Figures 12 and 13) INH to Output	R _L = 300 Ω , C _L = 35 pF (Figures 4 and 5)	2.5 3.0 4.5 5.5	2 2 1 1	7 5 4 3	12 10 9 8	2 2 1 1	15 15 12 12	2 2 1 1	15 15 12 12	ns
^t OFF	Turn–Off Time (Figures 12 and 13) INH to Output	R _L = 300 Ω , C _L = 35 pF (Figures 4 and 5)	2.5 3.0 4.5 5.5	2 2 1 1	7 5 4 3	12 10 9 8	2 2 1 1	15 15 12 12	2 2 1 1	15 15 12 12	ns
t _{trans}	Transition Time (Channel Selection Time) (Figure) Select to Output	R _L = 300 Ω , C _L = 35 pF (Figures and)	2.5 3.0 4.5 5.5	5 5 2 2	18 13 12 9	28 21 16 14	5 5 2 2	30 25 20 20	5 5 2 2	30 25 20 20	ns
t _{BBM}	Minimum Break-Before-Make Time	$V_{IS} = 3.0 \text{ V (Figure 3)}$ $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$	2.5 3.0 4.5 5.5	1 1 1	12 11 6 5		1 1 1 1		1 1 1		ns

^{*}Typical Characteristics are at 25°C.

		Typical @ 25, VCC = 5.0 V	
C _{IN}	Maximum Input Capacitance, Select/INH Input	8	pF
CNO or CNC	Analog I/O (switch off)	10	
C _{COM}	Common I/O (switch off)	10	
C _(ON)	Feedthrough (switch on)	20	

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			vcc	Typical	
Symbol	Parameter	Condition	٧	25°C	Unit
BW	Maximum On–Channel –3dB Bandwidth or Minimum Frequency Response (Figure 10)	V _{IN} = 0 dBm V _{IN} centered between V _{CC} and GND (Figure 7)	3.0 4.5 5.5	170 200 200	MHz
VONL	Maximum Feedthrough On Loss	V _{IN} = 0 dBm @ 100 kHz to 50 MHz V _{IN} centered between V _{CC} and GND (Figure 7)	3.0 4.5 5.5	-3 -3 -3	dB
V _{ISO}	Off-Channel Isolation (Figure 10)	f = 100 kHz; V _{IS} = 1 V RMS V _{IN} centered between V _{CC} and GND (Figure 7)	3.0 4.5 5.5	-93 -93 -93	dB
Q	Charge Injection Select Input to Common I/O (Figure 15)	$\begin{aligned} & \text{VIN} = \text{VCC to GND, FIS} = 20 \text{ kHz} \\ & \text{t}_{\text{f}} = \text{t}_{\text{f}} = 3 \text{ ns} \\ & \text{RIS} = 0 \ \Omega, \text{CL} = 1000 \text{ pF} \\ & \text{Q} = \text{CL} * \Delta \text{VOUT} \\ & \text{(Figure 8)} \end{aligned}$	3.0 5.5	1.5 3.0	рС
THD	Total Harmonic Distortion THD + Noise (Figure 14)	F_{IS} = 20 Hz to 100 kHz, R_L = Rgen = 600 Ω, C_L = 50 pF V_{IS} = 5.0 Vpp sine wave	5.5	0.1	%



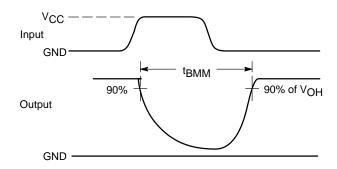
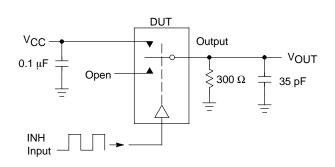


Figure 3. tBBM (Time Break-Before-Make)



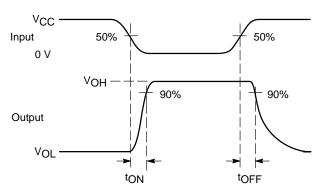
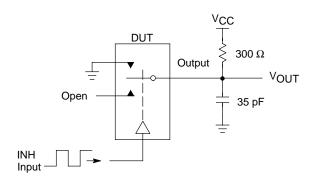


Figure 4. ton/toff



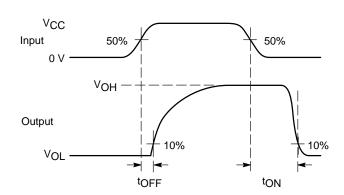


Figure 5. toN/toFF

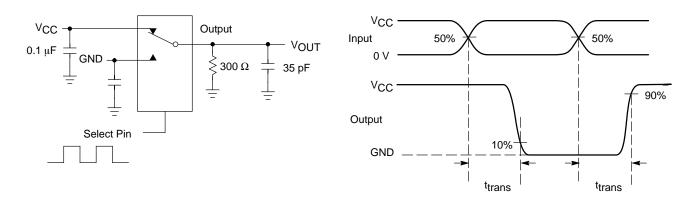
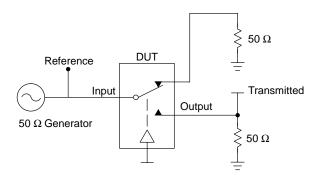


Figure 6. t_{trans} (Channel Selection Time)



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. $V_{\rm ISO}$, Bandwidth and $V_{\rm ONL}$ are independent of the input signal direction.

$$\begin{split} &V_{ISO} = \text{Off Channel Isolation} = 20 \text{ Log} \bigg(\frac{V_{OUT}}{V_{IN}} \bigg) & \text{for } V_{IN} \text{ at } 100 \text{ kHz} \\ &V_{ONL} = \text{On Channel Loss} = 20 \text{ Log} \bigg(\frac{V_{OUT}}{V_{IN}} \bigg) & \text{for } V_{IN} \text{ at } 100 \text{ kHz to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below VONL

Figure 7. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V_{ONL}

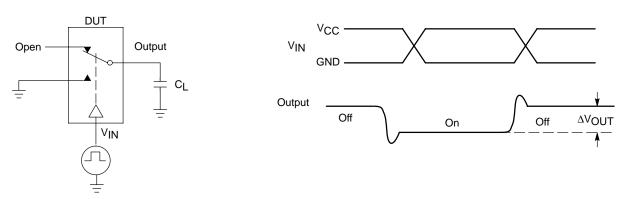


Figure 8. Charge Injection: (Q)

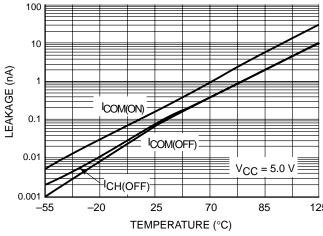


Figure 9. Switch Leakage versus Temperature

-100 **└** 0.01 125

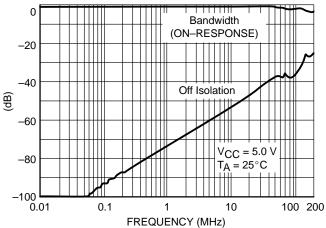
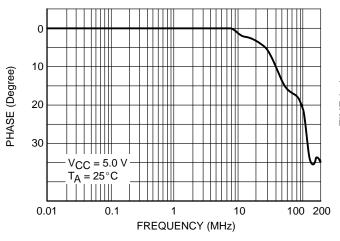
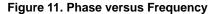


Figure 10. Bandwidth and Off-Channel Isolation





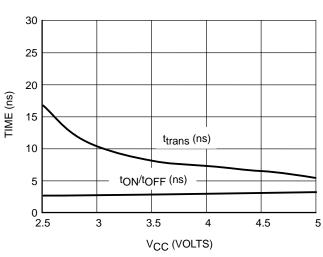


Figure 12. ton and toff versus VCC at 25°C

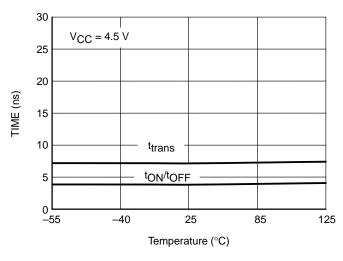


Figure 13. toN and toFF versus Temp

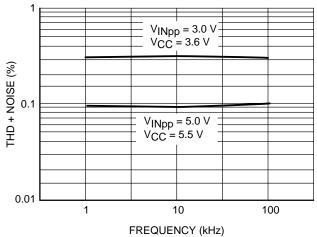


Figure 14. Total Harmonic Distortion **Plus Noise versus Frequency**

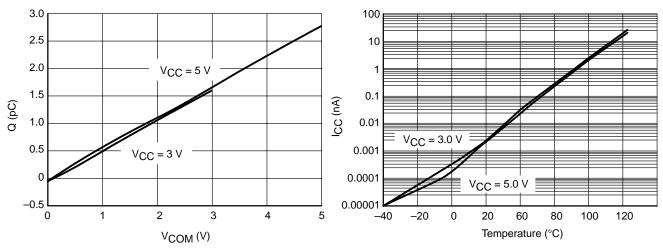


Figure 15. Charge Injection versus COM Voltage

Figure 16. ICC versus Temp, VCC = 3 V & 5 V

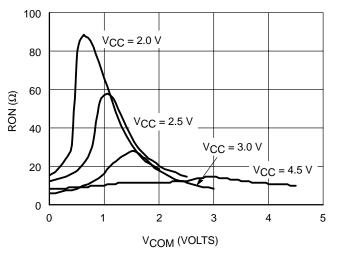


Figure 17. RON versus VCOM and VCC (@ 25°C

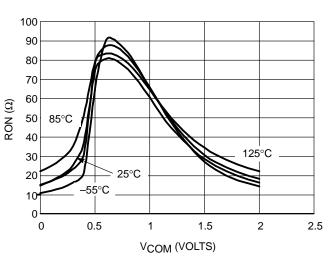


Figure 18. Ron versus V_{COM} and Temperature, V_{CC} 2.0 V

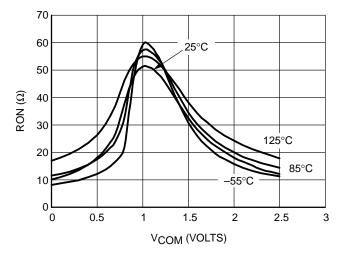


Figure 19. RoN versus V_{COM} and Temperature, V_{CC} = 2.5 V

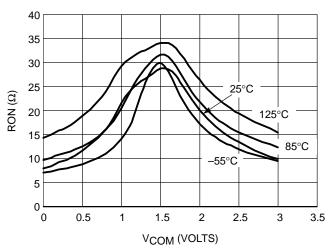
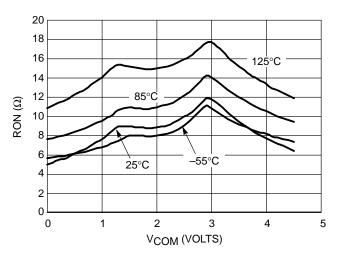


Figure 20. $R_{\mbox{ON}}$ versus $V_{\mbox{COM}}$ and Temperature, $V_{\mbox{CC}} = 3.0 \ \mbox{V}$



18 16 125°C 14 12 $\mathsf{RON}\left(\Omega\right)$ 10 85°C 8 -55°C 6 25°C 4 2 0 0 2 3 5 6 V_{COM} (VOLTS)

Figure 21. RoN versus VCOM and Temperature, VCC = 4.5 V

Figure 22. R_{ON} versus V_{COM} and Temperature, V_{CC} = 5.0 V

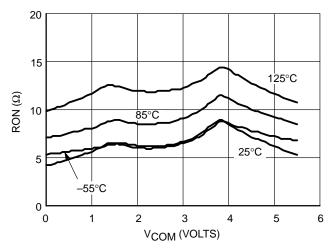


Figure 23. RoN versus VCOM and Temperature, VCC = 5.5 V

DEVICE ORDERING INFORMATION

		Device Nom	enclature				
Device Order Number	Circuit Indicator	Technology	Device Function	Package Suffix	Package Type	Tape and Reel Size	
NLAS1053US	NL	AS	1053	US	US8	178 mm (7") 3000 Unit	

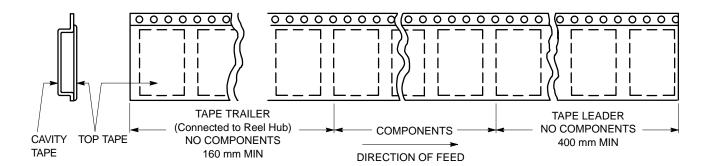


Figure 24. Tape Ends for Finished Goods

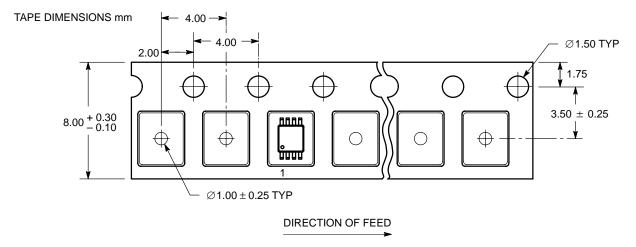


Figure 25. US8 Reel Configuration/Orientation

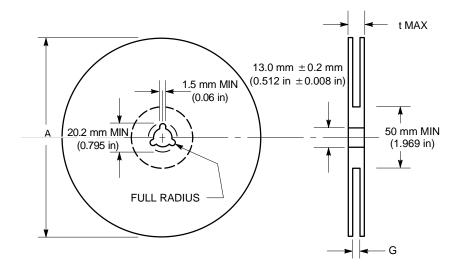


Figure 26. Reel Dimensions

REEL DIMENSIONS

Tape Size	T and R Suffix	A Max	G	t Max
8 mm	US	178 mm (7 in)	8.4 mm, + 1.5 mm, -0.0 (0.33 in + 0.059 in, -0.00)	14.4 mm (0.56 in)

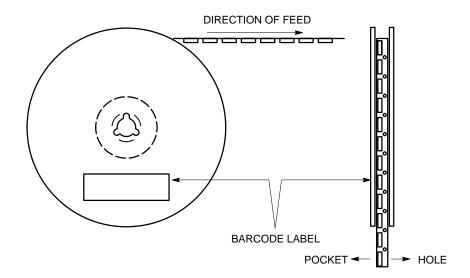
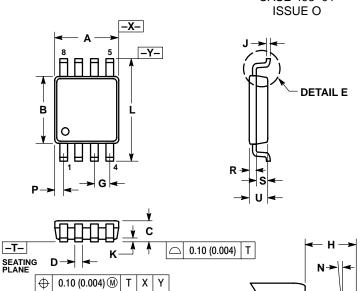


Figure 27. Reel Winding Direction

PACKAGE DIMENSIONS

US8 **US SUFFIX** CASE 493-01

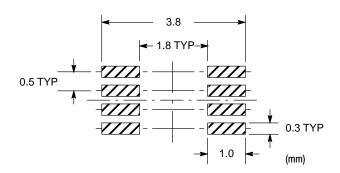


R 0.10 TYP

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS
- CONTROLLING DIMENSION: MILLIMETERS DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH. PROTRUSION AND GATE BURR SHALL NOT EXCEED 0.140 MM (0.0055") PER SIDE. 4. DIMENSION "B" DOES NOT INCLUDE
- INTER-LEAD FLASH OR PROTRUSION.
 INTER-LEAD FLASH AND PROTRUSION SHALL NOT E3XCEED 0.140 (0.0055") PER SIDE
- 5 LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0. 0203 MM. (300-800
- INCH).

 6. ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 (0.0002").

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.90	2.10	0.075	0.083	
В	2.20	2.40	0.087	0.094	
С	0.60	0.90	0.024	0.035	
D	0.17	0.25	0.007	0.010	
F	0.20	0.35	0.008	0.014	
G	0.50	BSC	0.020	BSC	
Н	0.40	REF	0.016	REF	
J	0.10	0.18	0.004	0.007	
K	0.00	0.10	0.000	0.004	
L	3.00	3.20	0.118	0.126	
M	0 °	6 °	0 °	6 °	
N	5 °	10 °	5 °	10 °	
P	0.28	0.44	0.011	0.017	
R	0.23	0.33	0.009	0.013	
S	0.37	0.47	0.015	0.019	
U	0.60	0.80	0.024	0.031	
٧	0.12	BSC	0.00	BSC	



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